

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74LVX14F, TC74LVX14FN, TC74LVX14FT**HEX SCHMITT INVERTER**

The TC74LVX14 is a high speed CMOS HEX SCHMITT INVERTER fabricated with silicon gate C²MOS technology. Designed for use in 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation. This device is suitable for low voltage and battery operated systems.

Pin configuration and function are the same as the TC74LVX04 but the inputs have hysteresis and with its schmitt trigger function, the TC74LVX14 can be used as a line receivers which will receive slow input signals.

An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage.

This device can be used to interface 5V to 3V systems and two supply systems such as battery back up.

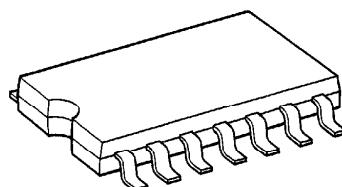
This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES

- High speed : $t_{pd} = 6.8\text{ns}$ (Typ.) ($V_{CC} = 3.3\text{V}$)
- Low power dissipation : $I_{CC} = 2\mu\text{A}$ (Max.) ($T_a = 25^\circ\text{C}$)
- Power down protection is provided on all inputs.
- Balanced propagation delays : $t_{pLH} \approx t_{pHL}$
- Low noise : $V_{OLP} = 0.5\text{V}$ (Max.)
- Pin and function compatible with 74HC14

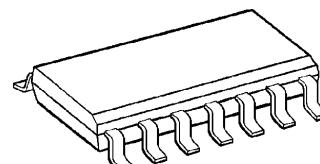
(Note) The JEDEC SOP (FN) is not available in Japan.

TC74LVX14F



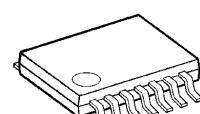
SOP14-P-300-1.27

TC74LVX14FN



SOL14-P-150-1.27

TC74LVX14FT



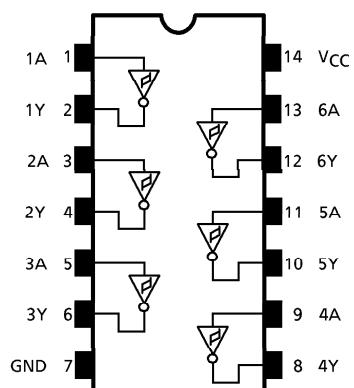
TSSOP14-P-0044-0.65

Weight

SOP14-P-300-1.27	: 0.18g (Typ.)
SOL14-P-150-1.27	: 0.12g (Typ.)
TSSOP14-P-0044-0.65	: 0.06g (Typ.)

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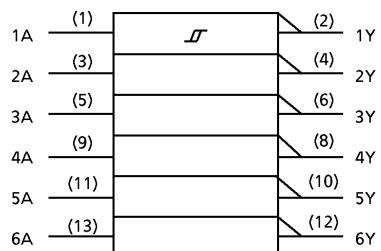
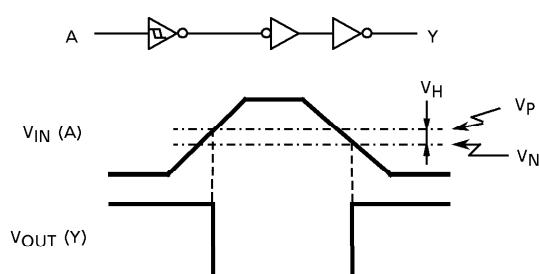
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PIN ASSIGNMENT

(TOP VIEW)

TRUTH TABLE

INPUTS	OUTPUTS
A	Y
L	H
H	L

IEC LOGIC SYMBOL**SYSTEM DIAGRAM, WAVEFORM**

961001EBA2'

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- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.

MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage Range	V_{CC}	-0.5~7.0	V
DC Input Voltage	V_{IN}	-0.5~7.0	V
DC Output Voltage	V_{OUT}	-0.5~ V_{CC} +0.5	V
Input Diode Current	I_{IK}	-20	mA
Output Diode Current	I_{OK}	± 20	mA
DC Output Current	I_{OUT}	± 25	mA
DC V_{CC} / Ground Current	I_{CC}	± 50	mA
Power Dissipation	P_D	180	mW
Storage Temperature	T_{stg}	-65~150	°C

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	2.0~3.6	V
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~ V_{CC}	V
Operating Temperature	T_{opr}	-40~85	°C

ELECTRICAL CHARACTERISTICS

DC characteristics

PARAMETER	SYM-BOL	TEST CONDITION	V_{CC} (V)	Ta = 25°C			Ta = -40~85°C		UNIT		
				MIN.	TYP.	MAX.	MIN.	MAX.			
Threshold Voltage	"H" Level	V_P	3.0	—	—	2.2	—	2.2	V		
	"L" Level	V_N	3.0	0.9	—	—	0.9	—			
Hysteresis Voltage	V_H		3.0	0.3	—	1.2	0.3	1.2	V		
Output Voltage	"H" Level	V_{OL}	$V_{IN} = V_{IL}$	$I_{OH} = -50\mu A$	2.0	1.9	2.0	—	1.9	V	
				$I_{OH} = -50\mu A$	3.0	2.9	3.0	—	2.9		
				$I_{OH} = -4mA$	3.0	2.58	—	—	2.48		
	"L" Level	V_{OL}	$V_{IN} = V_{IH}$	$I_{OL} = 50\mu A$	2.0	—	0.0	0.1	—		
				$I_{OL} = 50\mu A$	3.0	—	0.0	0.1	—		
				$I_{OL} = 4mA$	3.0	—	—	0.36	—		
Input Leakage Current	I_{IN}	$V_{IN} = 5.5V$ or GND		3.6	—	—	± 0.1	—	± 1.0	μA	
Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC}$ or GND		3.6	—	—	2.0	—	20.0	μA	

AC characteristics (Input $t_r = t_f = 3\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION	$T_a = 25^\circ\text{C}$			$T_a = -40\sim85^\circ\text{C}$		UNIT	
			V_{CC} (V)	C_L (pF)	MIN.	TYP.	MAX.		
Propagation Delay Time	t_{PLH}	(Note 1)	2.7	15	—	8.7	16.3	1.0 19.5	
				50	—	11.2	19.8	1.0 23.0	
	t_{PHL}		3.3 ± 0.3	15	—	6.8	10.6	1.0 12.5	
				50	—	9.3	14.1	1.0 16.0	
Output To Output Skew	t_{osLH} t_{osHL}		2.7	50	—	—	1.5	1.5	
			3.3 ± 0.3	50	—	—	1.5	1.5	
Input Capacitance	C_{IN}	(Note 2)	—	—	4	10	—	10	
Power Dissipation Capacitance	C_{PD}	(Note 3)	—	—	21	—	—	pF	

(Note 1) Parameter guaranteed by design.

$$(t_{osLH} = |t_{PLHm} - t_{PLHn}|, t_{osHL} = |t_{PHLm} - t_{PHLn}|)$$

(Note 2) Parameter guaranteed by design.

(Note 3) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

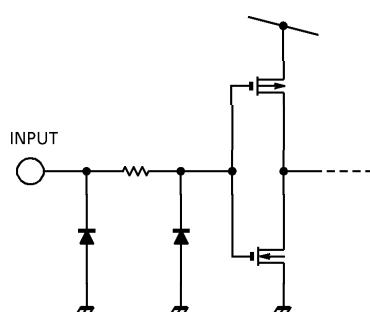
Average operating current can be obtained by the equation :

$$I_{CC(\text{opr.})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6 \text{ (per gate)}$$

Noise characteristics ($T_a = 25^\circ\text{C}$, Input $t_r = t_f = 3\text{ns}$, $C_L = 50\text{pF}$)

PARAMETER	SYMBOL	TEST CONDITION	V_{CC} (V)	TYP.	LIMIT	UNIT
Quiet Output Maximum Dynamic V_{OL}	VOLP	—	3.3	0.3	0.5	V
Quiet Output Minimum Dynamic V_{OL}	VOLV	—	3.3	-0.3	-0.5	V
Minimum High Level Dynamic Input Voltage	VIHD	—	3.3	—	2.2	V
Maximum Low Level Dynamic Input Voltage	VILD	—	3.3	—	0.9	V

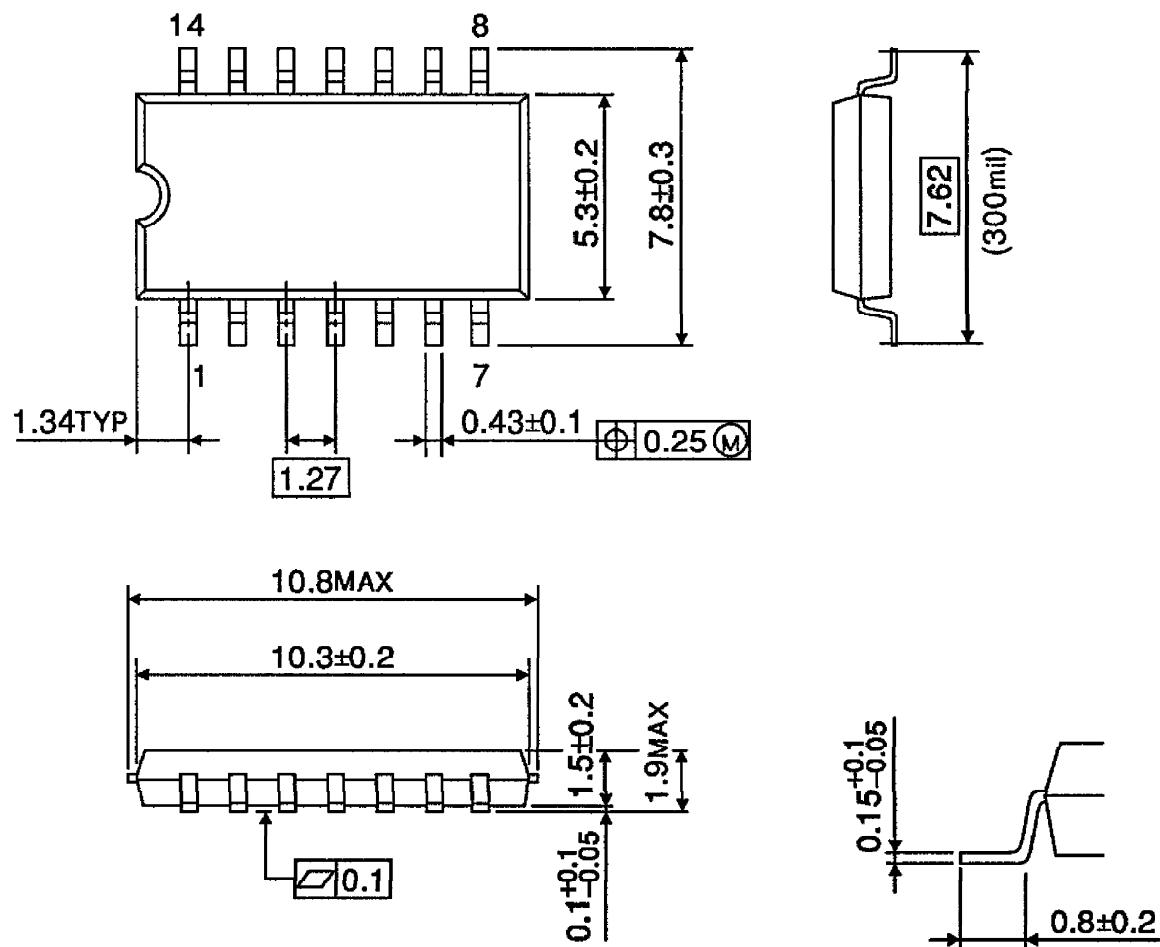
INPUT EQUIVALENT CIRCUIT



OUTLINE DRAWING

SOP14-P-300-1.27

Unit : mm

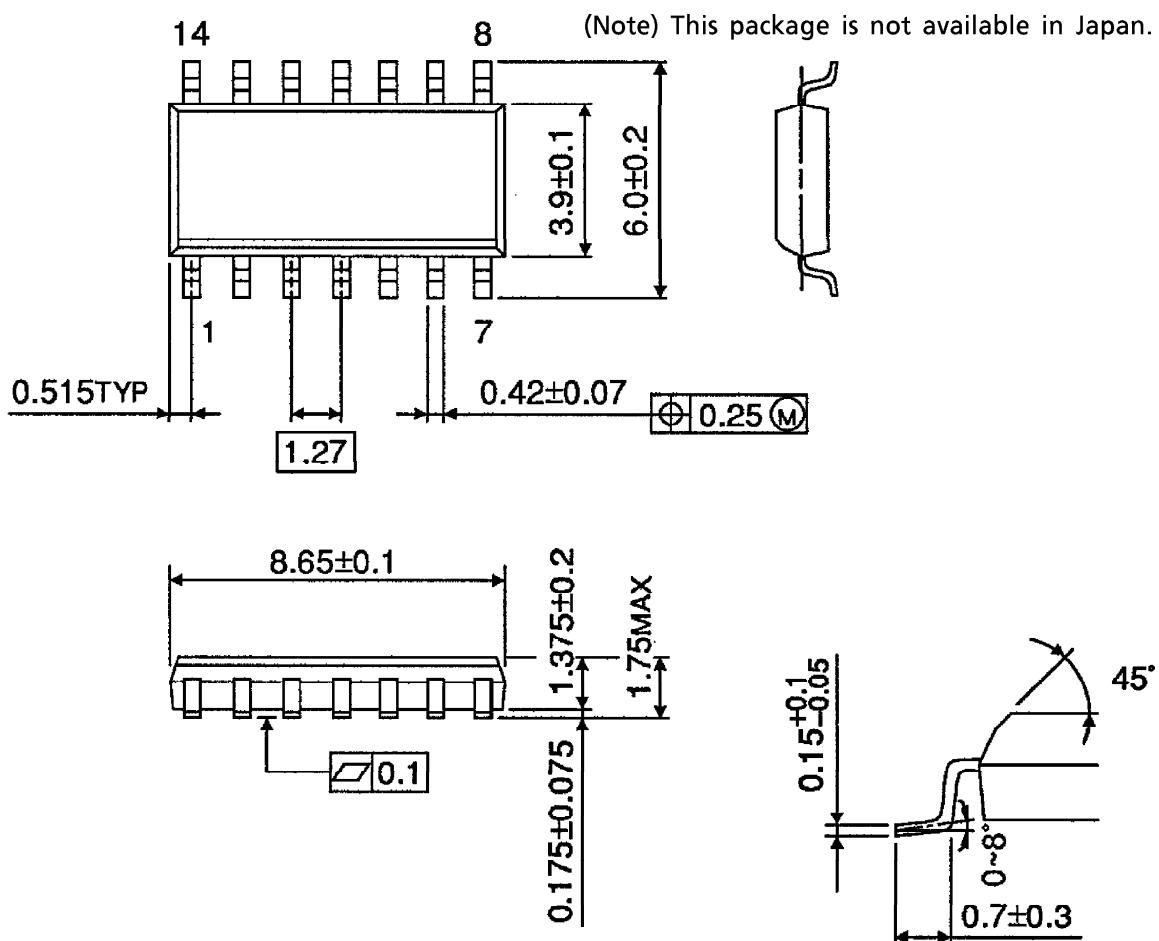


Weight : 0.18g (Typ.)

OUTLINE DRAWING

SOL14-P-150-1.27

Unit : mm

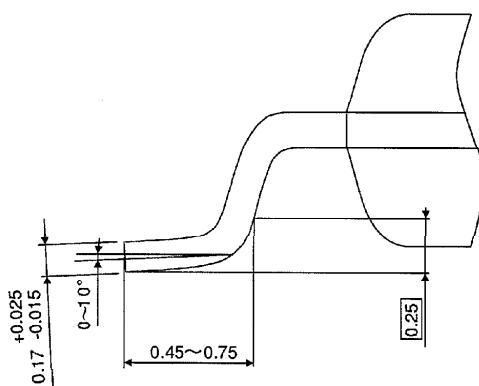
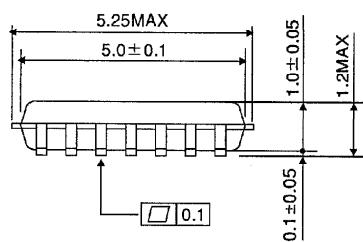
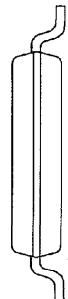
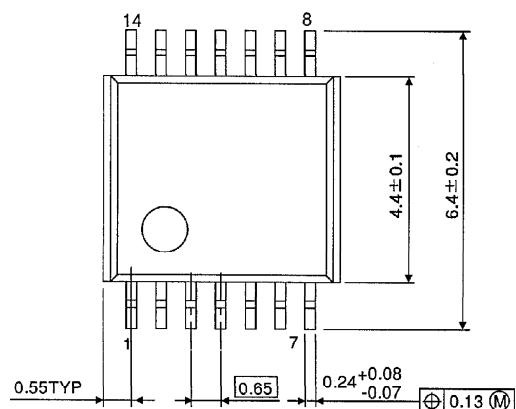


Weight : 0.12g (Typ.)

OUTLINE DRAWING

TSSOP14-P-0044-0.65

Unit : mm



Weight : 0.06g (Typ.)